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a valid OMB control number. **Attorney Docket Number** MSI-5 DECLARATION FOR UTILITY OR Hung Chang LIN First Named Inventor **DESIGN** PATENT APPLICATION COMPLETE IF KNOWN (37 CFR 1.63) **Application Number** Declaration Filing Date ☐ Declaration OR Submitted Submitted after Initial Group Art Unit . with Initial Filing (surcharge (37 CFR 1.16 (e)) Filing **Examiner Name** required)

As a below named invento	r, I hereby declare that:						
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names are listed below) of the	I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled:						
		CENTRO ENG IO WHICH & DE	itent is sought or	the invention e	ntitled:		
Adaptive MOS	FET Resistor						
the specification of which	(7)	le of the Invention)					
is attached hereto	1,72	~ or the interioring .		•			
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was filed on (MM/DD/	[as Unite	d States Applica	tion Number or I	PCT International		
Application Number	and w	res amended on (MM/DD/Y	m [(if applicable).		
I hereby state that I have reviewant amended by any amendment	mand and understand the		tified sections:	- :1	(ii applicable).		
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I hereby claim foreign priority certificate, or 365(a) of any PC	benefits under 35 U.S.C.	119(0) (4) 04 2650) -4					
certificate, or 365(a) of any PC America, listed below and have	T international application	on which designated at lea	ny foreign applic IST one country (alion(s) for pale other than the t	ent or inventor's		
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Name	Hung Chang LIN										
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		First Inventor:			DAP	etition I				nsigned inve	intor
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inventor's Signature		Hung Ch	angl	Pin	1				\neg	Date	10//14//03
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Application Number	
Filing Date	
First Named Inventor	Hung Chang LIN
Title	Adaptive MOSFET Resistor
Group Art Unit	
Examiner Name	
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Applicant/	t/Inventor	
X Assignee	of record of the entire interest. See 37 CFR 3.71.	
Statement	nt under 37 CFR 3.73(b) is enclosed. (Form PTO/SB/96).	
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